



Description

The eFuse is a 5V protection device with a bidirectional switch that incorporates input slew rate control to reduce input surge current and reverse current detection to prevent discharge to VCC from VOUT. The eFuse protection features include under voltage lockout, a fixed 2.5A current limit, trimmed fast response over voltage protection and thermal shutdown. The EN/FAULT line is a tri-state bidirectional interface that can be used to disable the output by pulling the line low through an external open drain device. If a thermal fault occurs, the voltage on the pin will go to an intermediate voltage indicating a fault and it can be connected to another device to cause simultaneous shut down. The SAS pin is an ESD protected interface that allows direct external control of the eFuse. Driving the SAS pin high pulls the enable line low causing the eFuse to shutdown and enter a low quiescent current state.

The integrated Isofet latches off when the reverse current is detected. This can be reset only by triggering the under voltage lock out, by EN/FAULT pin or when voltage on the output pin (VOUT) falls below the supply pin voltage (VCC) in AP91352.

The AP91352 is available in a standard Green W-QFN3020-12 package and is RoHS compliant.

Features

- SAS Disable
 - 2.1V Signal Disables the eFuse
 - ESD Compliant to1kV HBM and 500V CDM
- Integrated Isofet that latches off when reverse current is detected. Latch off is reset by
 - SAS pin
 - UVLO Trigger
 - EN/FAULT Pin
- Input Tolerant of Continuous 12V
- 50m Ω Typical Total on Resistance
- Fixed 2.5A Over Current Protection (OCP)
- Over Voltage Protection (OVP)
 - Trimmed 5.5V to 6.0V Fast Response
 - 50µs Latch off
- Fixed 13ms ±20% Slew Rate Control (SRC)
 - Over Temperature Protection (OTP)
- Under Voltage Lockout (UVLO)
- Thermally Efficient Low Profile Package, W-QFN3020-12
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

SAS DISABLE +5V eFUSE WITH INTEGRATED ISOFET

Pin Assignments



W-QFN3020-12

Applications

- HHD Drives
- SSD Drives
- Mother Board Power Management
- Printer Load Power Management
- Fan Drives



Typical Applications Circuit



Pin Descriptions

Pin Number	Pin Name	Description
1, 2, 3	VCC	Supply input, a 1μ F capacitor is needed to supply internal charge pump. The capacitor return should be connected directly to the GND pin.
4	SAS	SAS Disable, When this pin is pulled high to a voltage greater then 2.1V, the eFuse is turned off.
5	EN/FAULT	The EN/FAULT pin is a tri-state, bidirectional interface. It can be used to enable or disable the output of the device by pulling it to ground using an open drain device. If a thermal fault occurs, the voltage on this pin will go to an intermediate state to signal a monitoring circuit that the device is in thermal shutdown. It can also be connected to another device in this family to cause a simultaneous shutdown during thermal events.
6, 7, 8	NC	Do not connect on PCB, internally connected for production purpose
9, 10, 11	VOUT	Output: eFuse controlled output; a 20µF capacitor is needed for over voltage protection stability. The capacitor return should be connected directly to the GND pin.
12	GND	Ground
13	GND	Ground exposed pad



Functional Block Diagram



Absolute Maximum Ratings (Note 4) (@ T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Ratings	Units		
	Steady	y State	-0.3 to 12		
VCC	Input Voltage Transi	ent (100ms)	-0.3 to 15	V	
EN/FAULT	Enable Voltage		-0.3 to 6	V	
SAS	SAS Disable Voltage		-0.3 to 3.6	V	
VOUT	VOUT Voltage		-0.3 to 7.0	V	
ESD HBM	Human Body ESD Protection JESD22-A114	2000	V		
ESD CDM	Charged Device Model ESD Protection JESD	1000	V		
T _{A(max)}	Maximum Ambient Temperature	-40 to +125	°C		
T _{J(max)}	Maximum Junction Temperature	+150	°C		
T _{ST}	Storage Temperature	-65 to +150	°C		
PD	Power Dissipation ($T_A = +25^{\circ}C$) W-QFN3020-12		1.3	W	
R _{0JA}	Thermal Resistance, Junction to Ambient (0.5 sq in) W-QFN3020-12 (Note 5)		40	°C/W	

Notes: 4. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

5. For a device surface mounted on 25mm by 25mm by 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady state condition.

Recommended Operating Conditions (All specifications are for -10°C < T_A < +85°C, VCC = 5V, unless otherwise noted.)

Symbol	Parameter	Min	Тур	Max	Units
VCC	Input Voltage Range	3.6	-	12	V
T _A	Operating Ambient Temperature	-40	_	+85	°C



Electrical Characteristics (Note 6) (All specifications are for -10°C < T_A < +85°C, VCC = 5V, unless otherwise noted.)

Symbol	Parameters	Conditions	Min	Тур	Max	Unit		
Supply Curr	Supply Current							
		$EN = High, SAS = 0, I_{LOAD} = 0A$	_	_	300	μA		
lq	VCC Supply Current	Fault Latch off	_	100	_	μA		
		EN = Low	-	-	100	μA		
Power FET			1	1				
Proven	ON Registeres	T _A = +25°C	_	50	-	mΩ		
NDS(ON)		$T_{\rm J} = +80^{\circ}{\rm C}$	-	95	-	mΩ		
t _{ON-DLY}	Turn-on Delay	Enable I _D = 100mA, 1A Resistive Load	_	500	_	μs		
IDC	Continuous Current	T _A = +25°C, 0.5 sq in copper	_	2	-	А		
I _{OFF}	Off State Leakage	VCC = 12V, EN = Low		_	1	μA		
Slew Rate C	ontrol							
SRC	Slew Rate Control	EN to VOUT = 4.7V (Note 7)	10.4	13.0	15.6	ms		
Current Prot	ection		-	-				
ILIM	Current Limit	_	2.5	3.0	-	А		
I _{SHORT}	Short Circuit Current	_	2.2	3.0	_	А		
t _{ILIM}	Current Limit Response	_	5.5	_	40	μs		
Reverse Cur	rent Limit / Under Voltage Protection							
IQREVERSE	Fast Reverse Current Limit	(Note 8)	1	_	1.7	А		
tQREVERSE	Fast Reverse Current Limit Response Time	VCC dv/dt = -5V/100µs	5	_	10	μs		
UVLO	Under Voltage Lock Out	UVLO Rising	3.8	4.0	4.2	V		
UVLO-hys	Under Voltage Hysteresis	_	-	0.3	-	V		
-	Under Voltage Response	_	-	2.0	_	μs		
Over Voltage	e Protection							
OVP	Over Voltage Clamping	-	5.5	6	6.25	V		
tovp	Over Voltage Response	C _{OUT} = 20µF, dv/dt (VCC) = 0.5V/µs, VOUT < 6.5V	_	20	40	μs		
Thermal Pro	tection							
TH _{SD}	Shutdown Temperature	_	+130	+150	+200	°C		
Enable/Fault	Enable/Fault							
VL	Logic Level Low	Output Disabled (Note 7)	0.35	_	0.8	V		
VM	Logic Level Mid	Thermal Fault, Output Disabled (Note 7)	0.9	_	1.95	V		
V _H	Logic Level High	Output Enabled	2.1	_	3.3	V		
V _{MAX}	Maximum High State	_	3.4	_	5.2	V		
١L	Logic Low Sink Current	EN = 0V	_	-12	-20	μA		
Iн	Logic Level High	EN = 3.3V	_	_	1	μA		
FAN	Fan out	_	_	_	3	Units		



Electrical Characteristics (Cont.) (Note 6) (All specifications are for -10°C < T_A < +85°C, VCC = 5V, unless otherwise noted.)

Symbol	Parameters	Conditions	Min	Тур	Max	Unit
SAS Disable						
SASL	Logic Level Low	Output Enabled	0.35	_	0.7	V
SASH	Logic Level High	Output Disabled	0.8	1.0	2.1	V
SAS _{Hmax}	Maximum Pin Voltage	_	_	_	3.3	V
SAS- _{ΩIN}	Input Impedance	To GND	350	500	1000	kΩ
SAS-TDLY	Deglitch Filter	_	2	_	_	μs
_	Human Body JESD22-A114	_	1	_	_	kV
_	Charged Device JESD22-C101	_	500	_	_	V

Notes:

6. Typical data is measured at T_A = +25°C, VCC = 5V. The maximum and minimum parameters values over operating temperature range are not tested in production, they are guaranteed by design, characterization and process control.

7. The slew rate control is held in reset until the input voltage is greater than the UVLO rising threshold and Enable = High. The slew rate control is reset when input voltage drops below UVLO falling threshold, Enable changes from High to Mid or Low, SA = High or reverse current detection.

Reverse current detection will latch off the Isofet switch; In AP91352, this condition can be reset by under voltage lock out, by EN/FAULT and SAS pin, when VOUT falls below the supply pin voltage (VCC) by 100mV typical at T_A = +25°C, VCC = 5V.



Performance Characteristic



UVLO Hysteresis vs. Temperature









Over Voltage Clamping vs. Temperature



Off State Leakage vs. Temperature



AP91352 Document number: DS38109 Rev. 1 - 2



NEW PRODUCT

Performance Characteristic (Cont.)



Short Circuit Current vs. Temperature



Reverse Current Limit vs. Temperature





Input/Output Transient Response When Short Circuit

 $T_A=25^{\circ}C$, $V_{IN}=5V$, Output is short to GND



Reverse Current Limit Response Time vs. Temperature





Application Note

Theory of Operation

The AP91352 is a self protected, resettable electronic fuse. It monitors the input and output voltage, the output current and the die temperature. When the AP91352 is powered up it will ramp up the output voltage based on the fixed slew rate (see above electrical spec) and current will begin to flow. The Overcurrent Protection, Overvoltage Clamp, Under Voltage Lockout and Thermal Protection are internally set.

Also, integrated reverse blocking MOSFET would prevent back-drive from an active load inadvertently causing undetermined behavior in the application.

Overvoltage Clamping

The AP91352 monitor the input voltage and clamp output voltage once it exceeds 6.25V (MAX). This will allow for transient on the input for short periods of time. If the input voltage stays above 6.25V (MAX) for extended times the voltage drop across the FET with the load current will increase the die temperature and the thermal shutdown feature will protect the device and shut it down.

Under Voltage Lock Out

The input voltage of AP91352 is monitored by an UVLO circuit (under voltage lockout) if the input voltage drops below this threshold the output transistor will be pulled into a high impedance state.

Enable/Fault

The AP91352 has a tri state EN/FAULT pin. It is used to turn on and off the device with high and low signals from a GPIO, but can also indicate a thermal fault. When the EN/FAULT pin is pulled low the output is turned off, when the EN/FAULT pin is pulled high the output is turned on. Also, the EN/FAULT pin would be internally pulled high after VCC reach UVLO. In the event of a thermal fault the EN/FAULT pin will be pulled low to an intermediate voltage by an internal circuit. This can be used to chain up to 3 efuse together, like AP91352, NIS5132 (12V effuse), or NIS5135 (5V effuse) together that during a thermal shut down the linked devices turn off as well.

Due to this fault indication capability it should not be connected to any type of logic with an internal pull up device.

AP91352 connected to a 2nd device will latch off until the EN/FAULT pin has been pulled to low and then allowed to go back up to a high signal, or SAS pin has been toggled from High to Low or if the power has been cycled. Once the part starts up again it will go through the start-up ramp determined by the internal circuit, 13ms (typ).

Symbol	Description	Enable/Fault	eFuse State	Latching
UVLO	Under Voltage Lock Out	VL	Off	No
SAS _H	SAS Disable = 1	VL	Off	N/A
TH _{SD}	Thermal Shutdown	VM	Off	Yes
I _{REVERSE}	Reverse Current Protection	V _M	Off	(Note 8)
SASo	SAS Disable = Open	V _H	On	N/A
SASL	SAS Disable = 0	V _H	On	N/A
_	VCC > UVLO, No Fault	V _H	On	N/A

Table 1. EN/FAULT Signal Levels & Device Status

Thermal Protection

The AP91352 has an integrated temperature sensing circuit that protects the die in the event of over temperature. The trip point has been intentionally set high at +150°C (typ) to allow for increased trip times during high power transient events. The AP91352 will shut down current flow to the output when the die temperature reaches +150°C (typ). The AP91352 will restart after the Enable pin has been toggled or the input power has been cycled.

Even though the thermal trip point has been set high to allow for high current transients the circuit design should accomplish best thermal performance with good thermal layout of the PCB. It is not recommended to operate AP91352 above +150°C over extended periods of time.



Ordering Information



Devi Nevela en	Package	Packaging	Identification	7" Tape and Reel		
Part Number	Code	(Note 9)	Code	Quantity	Part Number Suffix	
AP91352MN1-DT8-7	DT8	W-QFN3020-12	P9	3000/Tape & Reel	-7	

Note 9: Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Marking Information

W-QFN3020-12

(Top View) XX: Identification Code Y: Year: 0~9 W: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week Y: Internal Code X: Internal Code

Part Number	Package	Identification Code	
AP91352MN1-DT8-7	W-QFN3020-12	P9	



Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

W-QFN3020-12



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

W-QFN3020-12



Dimensions	Value (in mm)
С	0.500
G	0.575
Х	0.650
X1	0.750
X2	0.350
X3	2.400
Y	0.300
Y1	0.450
Y2	0.900
Y3	1.050
Y4	3.400



Taping Orientation



Note 10: The taping orientation of the other package type can be found on our website at http://www.diodes.com/datasheets/ap02007.pdf.



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